

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

CPH3437 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		4.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	18	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.4		1.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2.5A	4	6.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =2A, V _G S=4.5V		28	39	mΩ
	RDS(on)2	ID=2A, VGS=4V		29	40	mΩ
	R _{DS} (on)3	I _D =1A, V _G S=2.5V		39	55	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		755		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		155		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		135		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		17		ns
Rise Time	tr	See specified Test Circuit.		100		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		68		ns
Fall Time	tf	See specified Test Circuit.		85		ns

Marking: ZM Continued on next page.

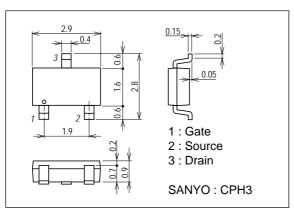
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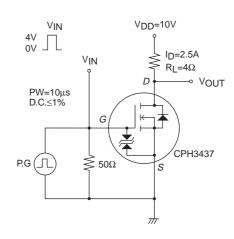
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		9.9		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		1.35		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		3.5		nC
Diode Forward Voltage	VSD	IS=4.5A, VGS=0		0.84	1.2	V

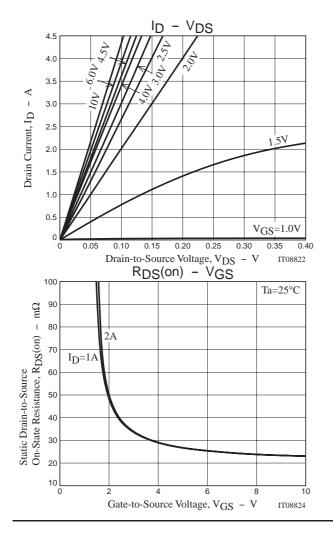
Package Dimensions

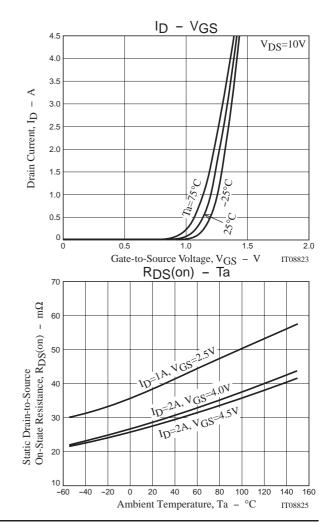
unit : mm 2152A

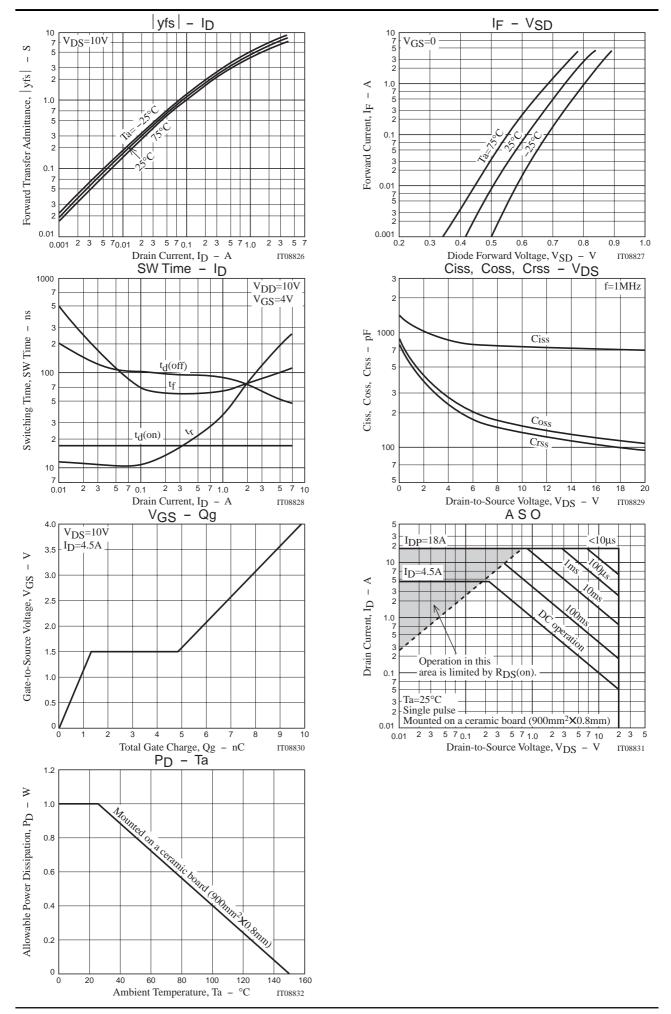


Switching Time Test Circuit









Note on usage: Since the CPH3437 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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